DTC143E

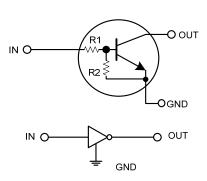
NPN SILICON TRANSISTOR

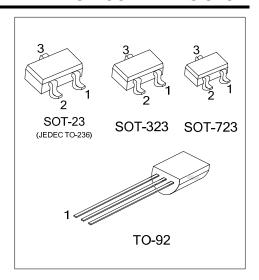
NPN DIGITAL TRANSISTOR (BUILT-IN RESISTORS)

■ FEATURES

- * Built-in bias resistors that implies easy ON/OFF applications.
- * The bias resistors are thin-film resistors with complete isolation to allow negative input.

■ EQUIVALENT CIRCUIT

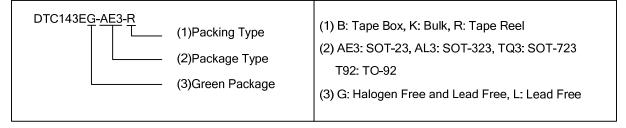




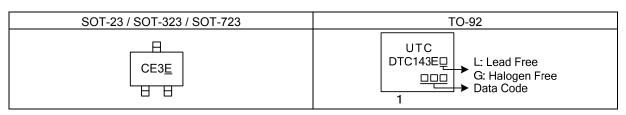
■ ORDERING INFORMATION

Ordering Number		Daakasa	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
-	DTC143EG-AE3-R	SOT-23	G	I	0	Tape Reel	
-	DTC143EG-AL3-R	SOT-323	G	I	0	Tape Reel	
-	DTC143EG-AQ3-R	SOT-723	G	I	0	Tape Reel	
DTC143EL-T92-B	DTC143EG-T92-B	TO-92	G	0	Ī	Tape Box	
DTC143EL-T92-K	DTC143EG-T92-K	TO-92	G	0	I	Bulk	

Note: Pin Assignment: G: GND I: IN O: OUT



■ MARKING



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■ **ABSOLUTE MAXIMUM RATINGS**(T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage		V_{CC}	50	V
Input Voltage		V_{IN}	-10 ~ +30	V
Output Current		Ιc	100	mA
Power Dissipation	SOT-23/ SOT-323	P _D	400	mW
	SOT-723		125	mW
	TO-92		625	mW
Junction Temperature		TJ	150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

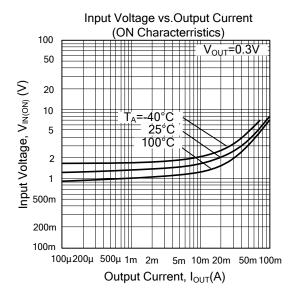
■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

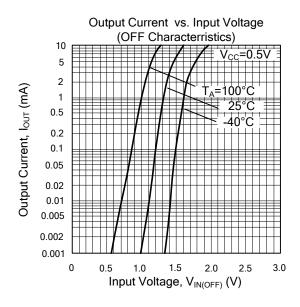
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input Voltage	$V_{IN(OFF)}$	$V_{CC} = 5V$, $I_{OUT} = 100\mu A$			0.5	V
	$V_{IN(ON)}$	$V_{OUT} = 0.3V$, $I_{OUT} = 20mA$	3			V
Output Voltage	$V_{OUT(ON)}$	$I_{OUT}/I_{IN} = 10 \text{mA}/0.5 \text{ mA}$		0.1	0.3	V
Input Current	I _{IN}	V _{IN} = 5V			1.8	mA
Output Current	I _{OUT(OFF)}	$V_{CC} = 50V$, $V_{IN} = 0V$			0.5	μΑ
DC Current Gain	h_{FE}	$V_{OUT} = 5V$, $I_{OUT} = 10mA$	20			
Input Resistance	R_1		3.29	4.7	6.11	ΚΩ
Resistance Ratio	$\frac{R_2}{R_1}$		0.8	1	1.2	
Transition Frequency	f_T	$V_{CE} = 10V$, $I_{E} = -5mA$, $f = 100MHz$ (Note)		250		MHz

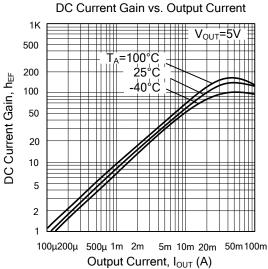
Note: Transition frequency of the device

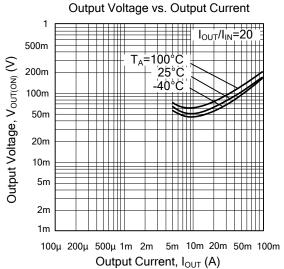
^{2.} Device mounted on PCB 50mm × 50mm × 1.6mm

■ TYPICAL CHARACTERISTIC









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